

# GPTN5061

## PHASE CONTROLLED SCR

High reliability operation  
 DC power supply  
 AC drives

**VOLTAGE UP TO** 4200 V  
**AVERAGE CURRENT** 610 A  
**SURGE CURRENT** 7.5 kA

### BLOCKING CHARACTERISTICS

Characteristic	Conditions	Value
VRRM	Repetitive peak reverse voltage	4200 V
VRSM	Non-repetitive peak reverse voltage	4300 V
VDRM	Repetitive peak off-state voltage	4200 V
IDRM	Repetitive peak off-state current, max.	VDRM, single phase, half wave, T <sub>j</sub> = T <sub>jmax</sub>
IRRM	Repetitive peak reverse current, max.	VRRM, single phase, half wave, T <sub>j</sub> = T <sub>jmax</sub>

### ON-STATE CHARACTERISTICS

I <sub>T(AV)</sub>	Average on-state current	Sine wave, 180° conduction, Th = 55 °C	610 A
I <sub>T(RMS)</sub>	R.M.S. on-state current	Sine wave, 180° conduction, Th = 55 °C	958 A
I <sub>TSM</sub>	Surge on-state current	Non rep. half sine wave, 50 Hz, V <sub>R</sub> = 0 V, T <sub>j</sub> = T <sub>jmax</sub>	7.5 kA
I <sup>2</sup> t	I <sup>2</sup> t for fusing coordination		281 kA <sup>2</sup> s
V <sub>T(TO)</sub>	Threshold voltage	T <sub>j</sub> = T <sub>jmax</sub>	1.297 V
r <sub>T</sub>	On-state slope resistance	T <sub>j</sub> = T <sub>jmax</sub>	0.935 mΩ
V <sub>TM</sub>	Peak on-state voltage, max	On-state current I <sub>T</sub> = 1500 A, T <sub>j</sub> = T <sub>jmax</sub>	2.70 V
I <sub>H</sub>	Holding current, max	T <sub>j</sub> = 25 °C	300 mA
I <sub>L</sub>	Latching current, typ	T <sub>j</sub> = 25 °C	700 mA

### TRIGGERING CHARACTERISTICS

V <sub>GT</sub>	Gate trigger voltage	T <sub>j</sub> = 25 °C, V <sub>D</sub> = 5 V	3.0 V
I <sub>GT</sub>	Gate trigger current	T <sub>j</sub> = 25 °C, V <sub>D</sub> = 5 V	250 mA
V <sub>GD</sub>	Non-trigger voltage	V <sub>D</sub> = 67% VRRM, T <sub>j</sub> = T <sub>jmax</sub>	0.3 V
P <sub>GM</sub>	Peak gate power dissipation	Pulse width 1 ms	150 W
P <sub>G(AV)</sub>	Average gate power dissipation		3 W
I <sub>FGM</sub>	Peak gate current		10 A
V <sub>FGM</sub>	Peak gate voltage (forward)		12 V
V <sub>RGM</sub>	Peak gate voltage (reverse)		10 V

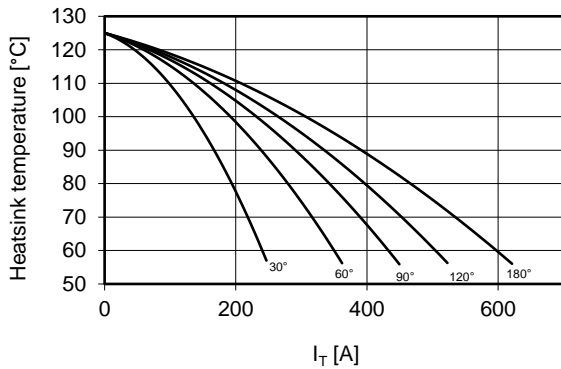
### SWITCHING CHARACTERISTICS

di/dt	Critical rate of rise of on-state current	Non rep. - T <sub>j</sub> = T <sub>jmax</sub>	150 A/μs
dV/dt	Critical rate of rise of off-state voltage	T <sub>j</sub> = T <sub>jmax</sub>	1000 V/μs
t <sub>q</sub>	Turn-off time, typ	T <sub>j</sub> = T <sub>jmax</sub> , I <sub>T</sub> = 2000 A, di/dt = -5 A/μs VR = 200 V, VD = 67% VDRM, dV/dt = 20 V/μs	μs

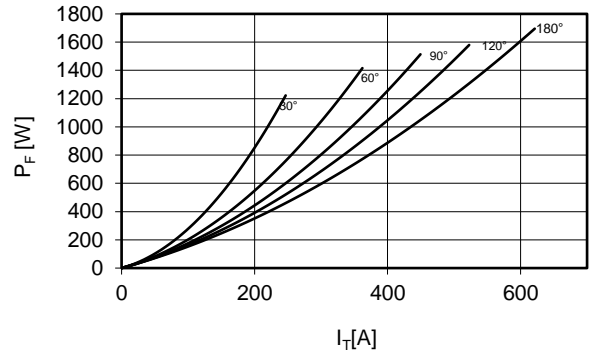
### THERMAL AND MECHANICAL CHARACTERISTICS

R <sub>th(j-c)</sub>	Thermal resistance (junction to case)	Double side cooled	0.032 °C/W
R <sub>th(c-h)</sub>	Thermal resistance (case to heatsink)	Double side cooled	0.007 °C/W
T <sub>jmax</sub>	Max operating junction temperature		125 °C
T <sub>stg</sub>	Storage temperature		-40 / 125 °C
F	Clamping force ± 5%		12 kN
	Mass		300 g

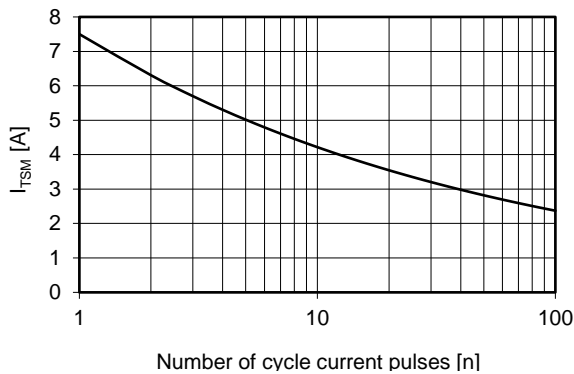
Current rating - sine wave



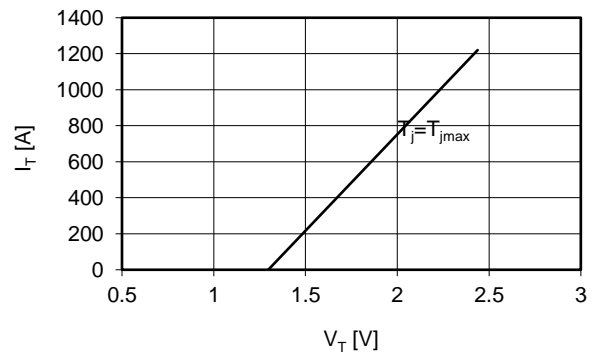
Power loss - sine wave



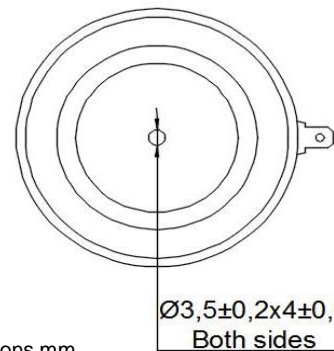
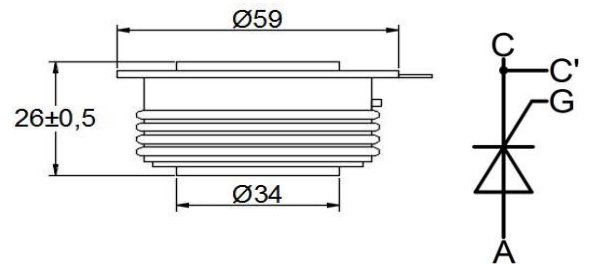
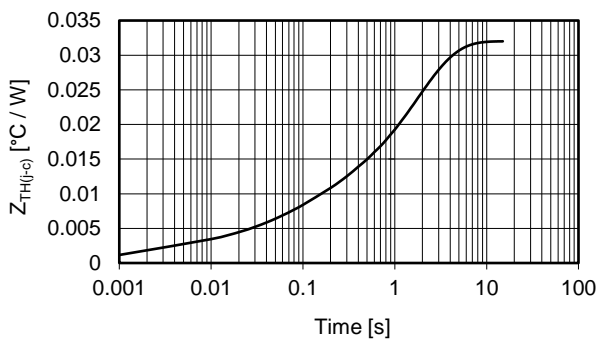
Maximum surge current d.s. cooled



On-state voltage drop



Thermal impedance (j-c)



**Ordering information GPTN5061-VVGL**

- VV**: blocking voltage / 100 (e.g. 42 for 4200 V)
- G**: trigger lead type (**S** = straight **T** = twisted **blank** = no leads)
- L**: trigger lead length x 100mm (**3 - 4 - 5 - 7 blank** = no leads)

dimensions mm

In the interest of product improvement Green Power Solutions reserves the right to change any specification given in this data sheet without notice.